

## MicroPower , Ultra-Sensitive CMOS Hall IC

### General Description

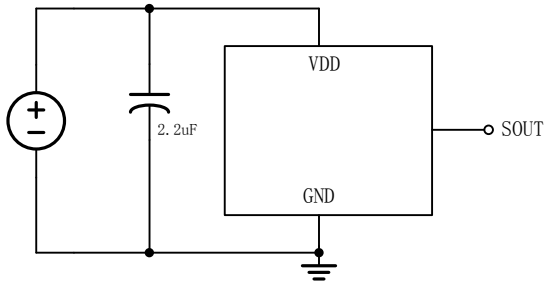
LN4916 is with proprietary Hall effect plate and single CMOS output driver, mainly designed for battery-powered, hand-held equipment (such as Cellular and Cordless Phone, PDA). When south-pole of sufficient strength on chip or north-pole of sufficient strength under chip, the LN4916 will turn on the SOUT output.

While the magnetic flux density (B) is larger than operate point BOP(s), the SOUT will be turned on (low), the output is held until B is lower than release point BRP(s), then turned off (high).

### Package

- SOT-553

### Typical Application Circuit



### Features

- 2.0V to 4.5V battery operation
- Operation with South Pole
- Chopper stabilized
- Superior temperature stability
- Extremely Low Switch-Point Drift
- Insensitive to Physical Stress
- Good RF noise immunity
- ESD HBM bigger than 4kV
- Lead Free Finish/RoHS Compliant

### Application

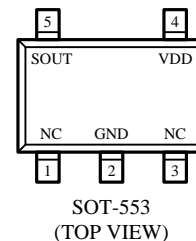
- Mobile phones and Portable electronic devices
- Notebook

### Ordering Information and Marking

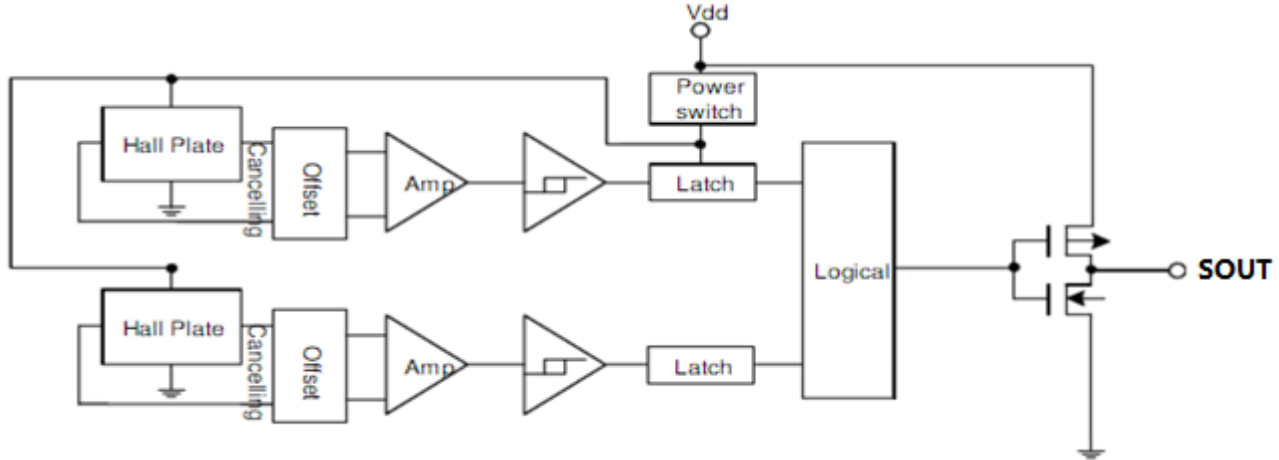
Order Name	Package	Marking
LN4916KR	SOT-553	16KY

### Pin Configuration

Pin Number	Pin Name	Function Description
<b>SOT-553</b>		
1	NC	No Connect
2	GND	Ground
3	NC	No Connect
4	VDD	Power
5	SOUT	South Output



## ■ Function Block Diagram



## ■ Absolute Maximum Ratings

Symbol	Characteristics	Values	Unit
V <sub>DD</sub>	Supply voltage	1.65~5	V
I <sub>DD</sub>	Operating current	-1~4.5	mA
V <sub>OUT</sub>	Output voltage	-0.3~5	V
I <sub>OUT</sub>	Output current	-1~2.0	mA
T <sub>S</sub>	Storage temperature range	-40~+150	°C
T <sub>J</sub>	Maximum junction temperature	150	°C
-	ESD Protection	4000	V

## ■ Electrical Characteristics

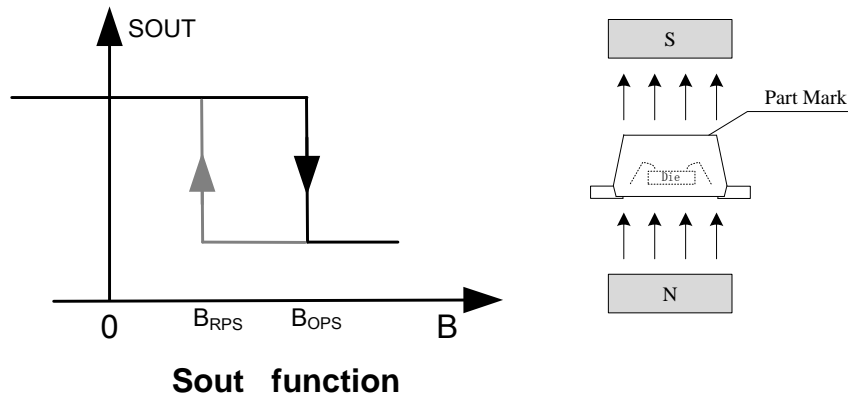
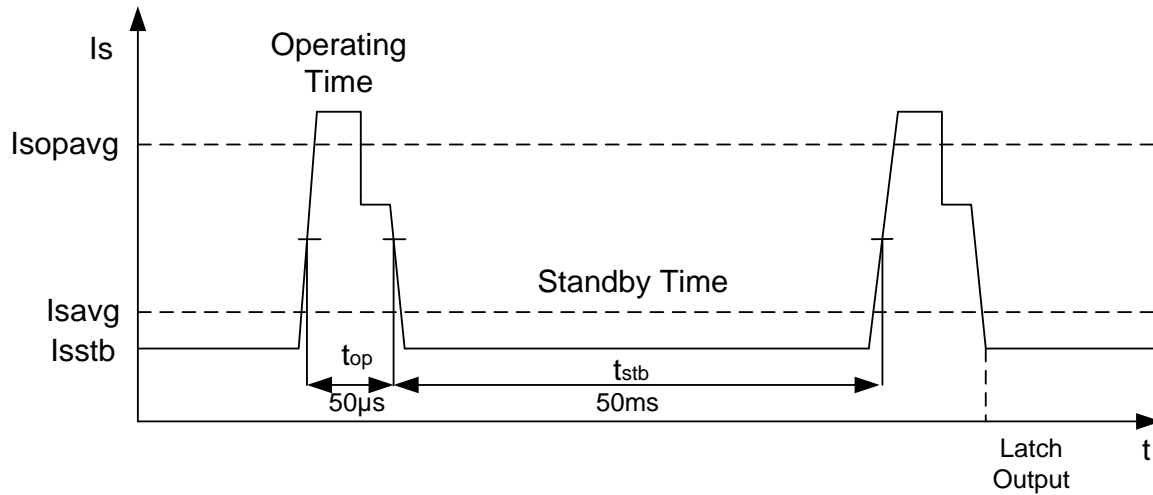
AC/DC Characteristics (T<sub>A</sub>=+25°C, V<sub>DD</sub>=3.0V, Unless otherwise specified)

Symbol	Characteristic	Conditions	Min	Typ	Max	Unit
V <sub>DD</sub>	Supply voltage	—	2.0	—	4.5	V
I <sub>SAVG</sub>	Averaged supply current		3	5	7	uA
I <sub>SOPAVG</sub>	Averaged current during operating time		0.5	0.7	1	mA
I <sub>SOPT</sub>	Peak current during operating time				2	mA
I <sub>SSTB</sub>	Supply current during standby time		1		2	uA
V <sub>OH</sub>	Output High Voltage	I <sub>OUT</sub> =-0.5mA	2.7	2.9		V
V <sub>OL</sub>	Output low Voltage	I <sub>OUT</sub> =0.5mA		0.1	0.3	V
t <sub>r</sub>	Output rise time	R <sub>L</sub> =2.7KΩ C <sub>L</sub> =10pF		0.5	1	us
t <sub>f</sub>	Output fall time	R <sub>L</sub> =2.7KΩ C <sub>L</sub> =10pF		0.1	1	us
t <sub>op</sub>	Operating time		40	50	60	us
t <sub>stb</sub>	Standby time		40	50	60	ms
t <sub>op</sub> /t <sub>stb</sub>	Duty cycle			0.1		%
t <sub>stu</sub>	Start-up time of IC			7	13	us

## ■ Magnetic Characteristics

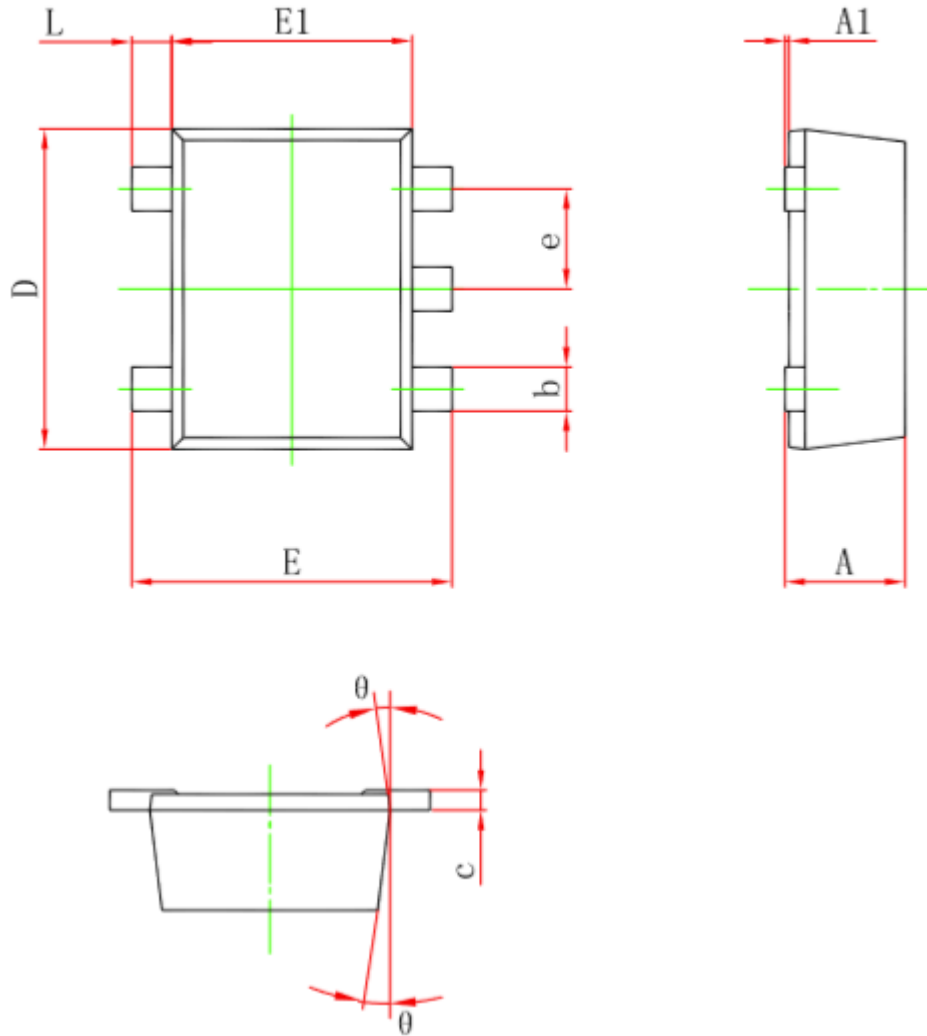
( $T_A=+25^{\circ}\text{C}$ ,  $V_{DD}=3.0\text{V}$ , Unless otherwise specified)

Symbol	Min	Typ	Max	Unit
BOPS	2	3.5	5.5	mT
BRPS	1	1.8	4.0	mT



**Package**

- SOT-553



Symbol	Dimensions In Millimeters		Dimensions in inches	
	Min.	Max.	Min.	Max.
A	0.525	0.600	0.021	0.024
A1	0.000	0.050	0.000	0.002
e	0.450	0.550	0.018	0.022
c	0.090	0.160	0.004	0.006
D	1.500	1.700	0.059	0.067
b	0.170	0.270	0.007	0.011
E1	1.100	1.300	0.043	0.051
E	1.500	1.700	0.059	0.067
L	0.100	0.300	0.004	0.012
θ	7 °REF.		7 °REF.	